

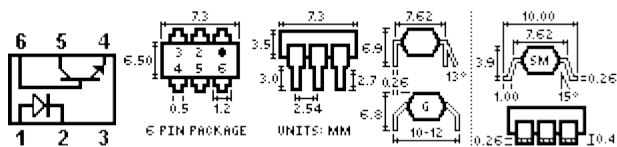
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## H11AV1X, H11AV2X, H11AV3X OPTICALLY COUPLED ISOLATOR TRANSISTOR OUTPUT

### Circuit



### 0884 VDE FEATURES

- Rated Impulse Voltage (Transient Overvoltage):  $V_{IOTM}=6$  kVpeak
- Insulation Test Voltage (Partial Discharge Test):  $V_{PD}=1.4$  kVpeak
- Rated Insulation Voltage (RMS includes d.c.):  $V_{IOWM}=600$  VRMS (848 Vpeak)
- Rated Recurring Peak Voltage (repetitive):  $V_{IORM}=600$  VRMS
- Isolation Materials: According to UL 94
- Creeping Current Resistance: According to VDE 0303 Part 1/06.84 (IEC 112)
- Climatic Classification: 55/100/21 (IEC 68 Part 1)
- Comparative Tracking Index: CTI 275 (VDE 0109/12.83\*)
- Pollution Degree: 2 (VDE 0109/12.83\*)
- (\*Identical with VDE 0110 Part 1/01.89)

### Description

The H11 AV series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode and an NPN silicon phototransistor mounted in a standard 6-pin dial-in-line package. Surface Mount Option Available.

The product type number consists of the basic product type followed by the letter "X" which indicates VDE

0884 approval of the basic part. Letter "X" supercedes letter "V" which denoted the now obsolete VDE 0883 approval.

For 10mm lead spread requirement add suffix G.

For surface mount requirements add suffix SM.

## Applications

These couplers meet the requirements of the following Equipment Standards:

VDE 0109/12.83, VDE 0110/01.89:

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation).

Application class I-IV at mains voltages  $\leq 300V$ .

Application class I-III at mains voltages  $\leq 600V$ .

VDE 0804/05.89:

Telecommunication Apparatus and Data Processing

VDE 0805/05.90 (IEC 950):

Data Processing Equipment and Office Machines (Option G only).

VDE 0860/05.89 (IEC 65):

Safety for mains-operated electronic and related apparatus for household.

UL 1577/09.89:

Standard for Safety Optical isolated switch systems. Package type K.

BS 415/1990; IEC 65/1985:

Safety requirements for mains-operated electronic and related apparatus for household and similar general use. Class II applications.

EN 60950/1989:

Specification for safety of information technology equipment including electrical business equipment (Option G only).

## Absolute Maximum Ratings ( $T_a=25^\circ C$ )

Storage Temperature:	$-55^\circ C$ to $+125^\circ C$
Operating Temperature:	$-55^\circ C$ to $+125^\circ C$
Lead Soldering:	$260^\circ C$ for 10s, 2mm from case
Input-to-Output Insulation Test Voltage:	6kV <sub>peak</sub> (Transient Overvoltage, $t=10s$ )

## Output Transistor

Collector-emitter Voltage $BV_{ce0}$ :	70V
Emitter-base Voltage $BV_{e0}$ :	7V
Collector-base Voltage $BV_{cb0}$ :	70V
Collector Current:	50mA
Collector Current:	100mA ( $t_p \leq 10ms$ , Duty Ratio 0.5)
Power Dissipation:	150mW
Derate Linearly:	2.00mW/ $^\circ C$ above $25^\circ C$

## Input Diode

Forward DC Current:	60mA
Reverse DC Voltage:	6V
Peak Forward Current:	3A (1 $\mu s$ p.w. 300pps)
Power Dissipation:	100mW
Derate Linearly:	1.33mW/ $^\circ C$ above $25^\circ C$

## Package

Total Power Dissipation: 250mW  
Derate Linearly: 3.3mW/°C above 25°C

## 0884 VDE Maximum Safety Ratings

Input Diode I<sub>si</sub>: 130mA max  
Output Transistor P<sub>si</sub>: 265mW max

### Coupled Device

Impulse Voltage V<sub>iotm</sub>: 6kV MAX  
Safety Temperature T<sub>si</sub>: 200°C

This device is suitable for safe electrical isolation *only* within the maximum safety ratings. This must be ensured by protective circuits in the applications.

## Note

This device is suitable for safe electrical isolation only within the maximum safety ratings. This must be ensured by protective circuits in the applications

## Insulation Rated Parameters (15°C to 35°C, 45-75% RH u.o.s.)

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
LOT SAMPLE TESTING				
Transient Overvoltage Rating (V <sub>IOTM</sub> )	Fig 1. V <sub>IOTM</sub> =6kVpeak, T <sub>INI</sub> =10s	No breakdown may occur		
Partial Discharge Measurement	Fig 1. V <sub>PD</sub> =1.05kVpeak T <sub>P</sub> =60s		5	pC
Insulation Resistance	V <sub>IO</sub> =500Vdc, T <sub>AMB</sub> =25°C	1E12		Ohm
	V <sub>IO</sub> =500Vdc, T <sub>AMB</sub> =100°C	1E11		Ohm
	V <sub>IO</sub> =500Vdc, T <sub>SI</sub> =200°C (construction test only)	1E9		Ohm
100% ROUTINE TESTING				
Partial Discharge Measurement	Fig 2. V <sub>PD</sub> =1.4kVpeak, T <sub>P</sub> =1s		5	pC

INPUT	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> =10mA	0.8		1.5	V
		I <sub>F</sub> =10mA, T <sub>A</sub> =-55°C	0.9		1.7	V
		I <sub>F</sub> =10mA, T <sub>A</sub> =+100°C	0.7		1.4	V
I <sub>R</sub>	Reverse Current	V <sub>R</sub> =6.0V			10	µA
	Capacitance	V <sub>R</sub> =0, f=1MHz		30		pF
<b>OUTPUT</b>						
BV <sub>CEO</sub>	Collector-emitter Voltage	I <sub>C</sub> =1mA	70			V
BV <sub>EBO</sub>	Emitter-base Voltage	I <sub>E</sub> =0.1mA	7			V
BV <sub>CBO</sub>	Collector-base Voltage	I <sub>C</sub> =0.1mA	70			V
I <sub>CEO</sub>	Collector-emitter Dark Current	V <sub>CE</sub> =10V, I <sub>F</sub> =0			50	nA
C <sub>CE</sub>	Collector-emitter Capacitance	V <sub>CE</sub> =10V, f=1MHz		2		pF
<b>COUPLED</b>		<b>TEST CONDITIONS</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
I <sub>C</sub> /I <sub>F</sub>	DC Current Transfer Ratio	I <sub>F</sub> =10mA, V <sub>CE</sub> =10V				
	H11AV1X		100		300	%
	H11AV2X		50			%
	H11AV3X		20			%
R <sub>IO</sub>	Input-to-Output Isolation Resistance	V <sub>IO</sub> =500V, (Note 1)	1000			Gohm
V <sub>CE(SAT)</sub>	Collector-emitter Saturation Voltage	I <sub>F</sub> =20mA, I <sub>C</sub> =2.0mA			0.4	V
C <sub>IO</sub>	Capacitance Input to Output	f=1MHz, (Note 1)			0.5	pF
t <sub>ON</sub>	Turn-on Time	V <sub>CC</sub> =10V, I <sub>C</sub> =2mA			15	µs
t <sub>OFF</sub>	Turn-off Time	R <sub>L</sub> =100ohm			15	µs

## Notes

1. Measured with input leads shorted together and output leads shorted together

## Isolation Characteristics

DESCRIPTION	SYMBOL	CHARACTERISTIC
Installation Category (DIN VDE0109, Dec 1983, Table 1)		I-IV H-III
IEC Climatic Category (DIN IEC 68 Part 1/09.80)		55/150/21
Pollution Degree (DIN VDE0109, Dec 1983)		2
Maximum Operating Isolation Voltage	V <sub>IO RM</sub>	630 V
Test Voltage Input/Output, Procedure B(1) V <sub>PR</sub> =1.6 x V <sub>IO RM</sub> , Sample Test with t <sub>p</sub> =1s, Partial Discharge<5pC	V <sub>PR</sub>	1000 V
Test Voltage Input/Output, Procedure A(1) V <sub>PR</sub> =1.2 x V <sub>IO RM</sub> , Type and Sampling Test with t <sub>p</sub> =60s, Partial Discharge<5pC	V <sub>PR</sub>	720 V
Maximum Permissible Overvoltage Transient Overvoltage, t <sub>TR</sub> =10s, Procedure A(1)	V <sub>TR</sub>	6000 V
Isolation Resistance, T <sub>SI</sub> V <sub>IO</sub> =500V	R <sub>IS</sub>	>=1 Gohm
<b>Safety Maximum Ratings (max permissible ratings in case of a fault):</b>		
Package Temperature	T <sub>SI</sub>	175 °C
Current (I <sub>F</sub> , P <sub>SI</sub> =0)	I <sub>SI</sub>	400 mA

Power (Output or Total Power Dissipation)	P <sub>SI</sub>	700 mW
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